

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Analog Devices Inc.](#)
[HMC-C050](#)

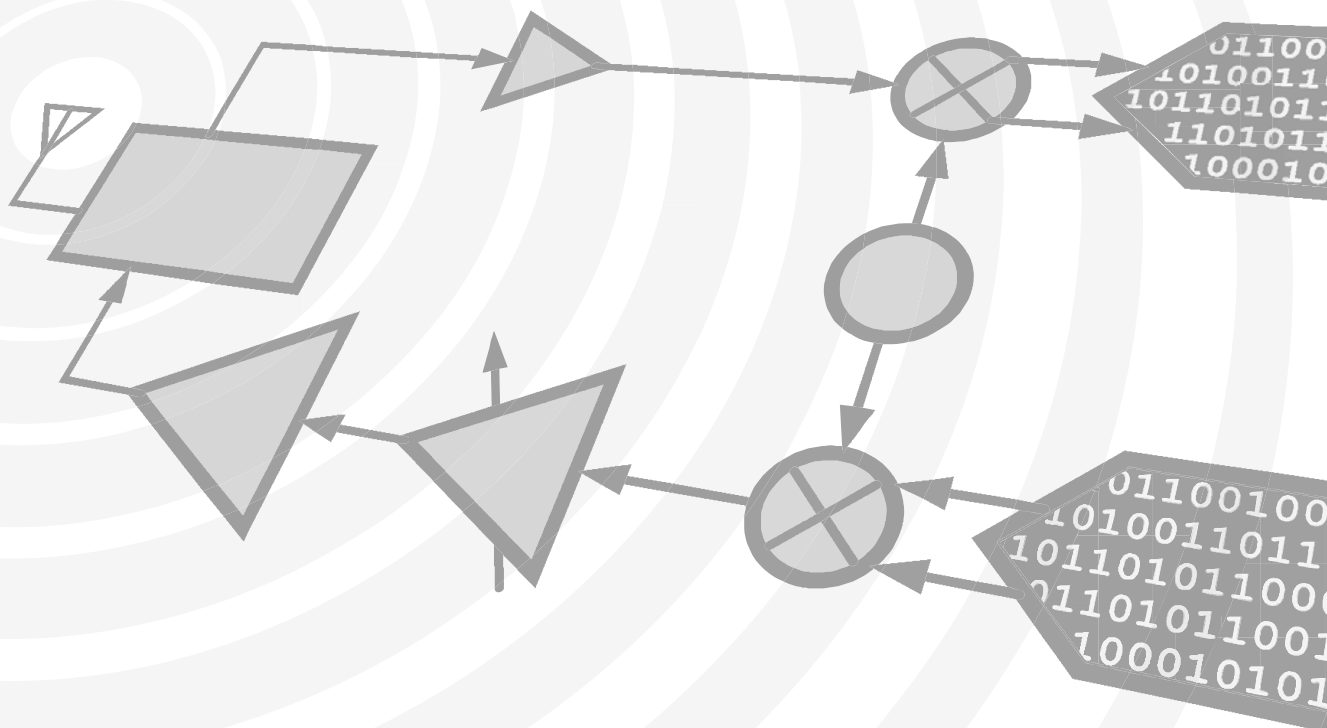
For any questions, you can email us directly:

sales@integrated-circuit.com



Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



THIS PAGE INTENTIONALLY LEFT BLANK



v01.0711



HMC-C050

ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

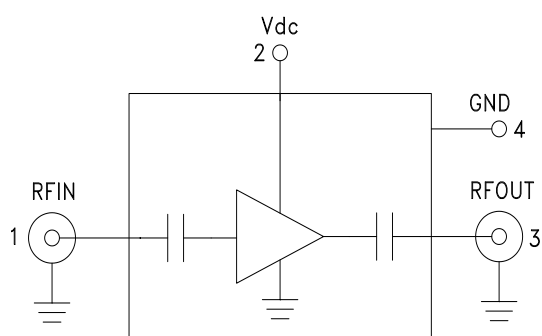


Typical Applications

The HMC-C050 is ideal for:

- Microwave Radio
- Military & Space
- Test Instrumentation
- VSAT

Functional Diagram



Features

Ultra Low Phase Noise: -160 dBc/Hz @ 10 kHz

Noise Figure: 5 dB

Gain: 13.5 dB

Output IP3: +22.5 dBm

50 Ohm Matched Input/Output

Single Supply Voltage: +5V

Hermetically Sealed Module

Field Replaceable SMA Connectors

-55 °C to +85 °C Operating Temperature

General Description

The HMC-C050 is a GaAs HBT Ultra Low Noise Amplifier in a miniature, hermetic module designed to operate between 2 and 18 GHz. This high dynamic range amplifier module provides 13.5 dB of gain, 5 dB noise figure and up to +22.5 dBm of OIP3 with a single supply of +5V. The ultra low phase noise contribution of -160 dBc/Hz, enables superior modulation accuracy within transceiver architectures. The wideband distributed amplifier I/O's are internally matched to 50 Ohms and DC blocked for robust performance. The module features removable SMA connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dc} = +5\text{V}$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	8 - 12.5			2 - 18			GHz
Gain	10.5	13.5		9.5	12.5		dB
Gain Flatness		± 1.2			± 2.2		dB
Gain Variation Over Temperature		0.021			0.027		dB/ °C
Noise Figure		4.5			6.5		dB
Input Return Loss		18			16		dB
Output Return Loss		17			15		dB
Output Power for 1 dB Compression (P1dB)	13	15		8	13		dBm
Saturated Output Power (Psat)		18.5			16		dBm
Output Third Order Intercept (IP3)		22.5			20		dBm
Phase Noise @ 100 Hz		-140			-150		dBc/Hz
Phase Noise @ 1 kHz		-150			-150		dBc/Hz
Phase Noise @ 10 kHz		-160			-150		dBc/Hz
Phase Noise @ 1 MHz		-165			-160		dBc/Hz
Supply Current		80	104		80	104	mA

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order Online at www.hittite.com



MICROWAVE CORPORATION

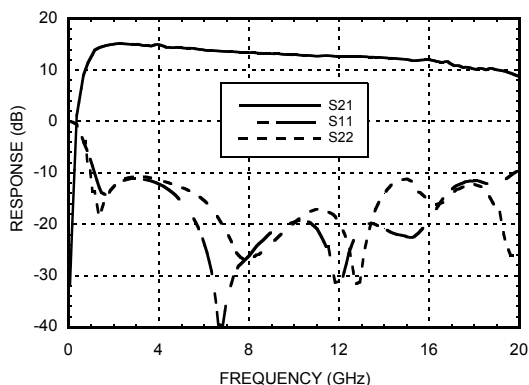
v01.0711



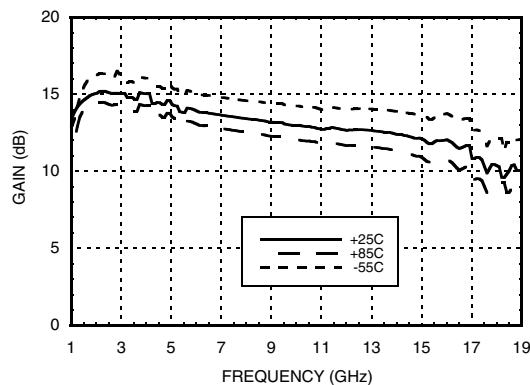
HMC-C050

ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

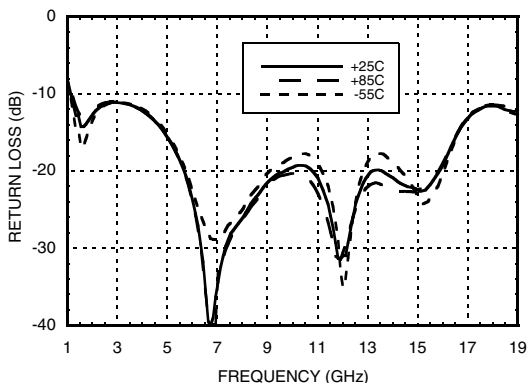
Gain & Return Loss



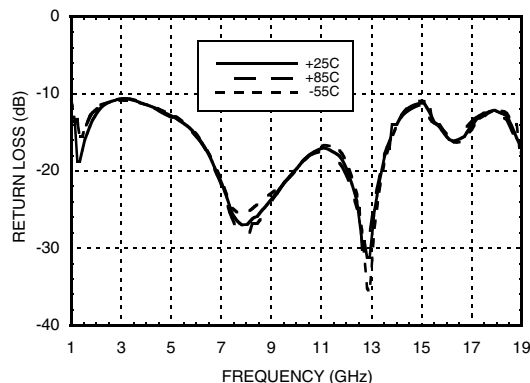
Gain vs. Temperature



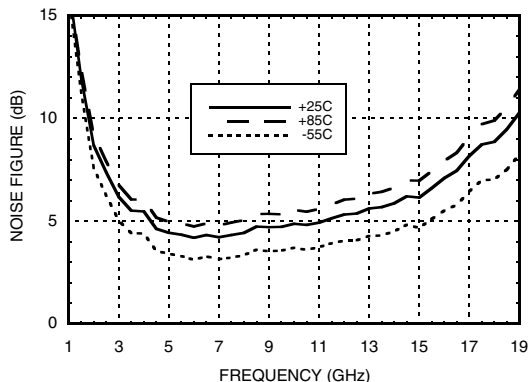
Input Return Loss vs. Temperature



Output Return Loss vs. Temperature



Noise Figure vs. Temperature





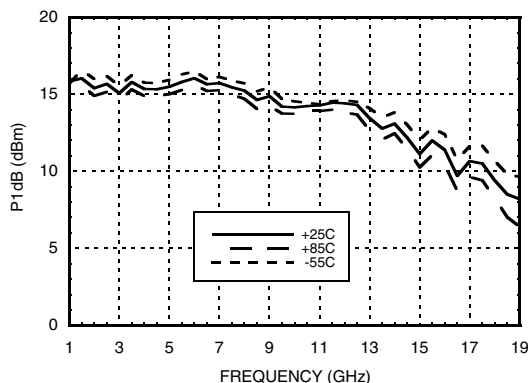
v01.0711



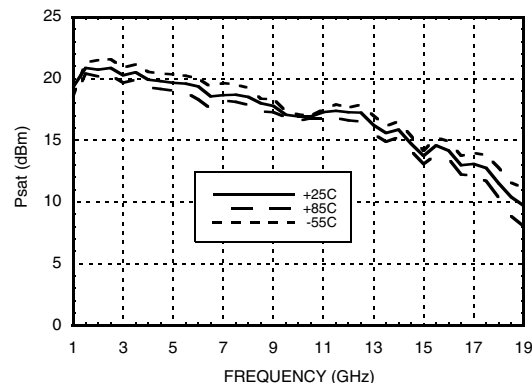
HMC-C050

ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

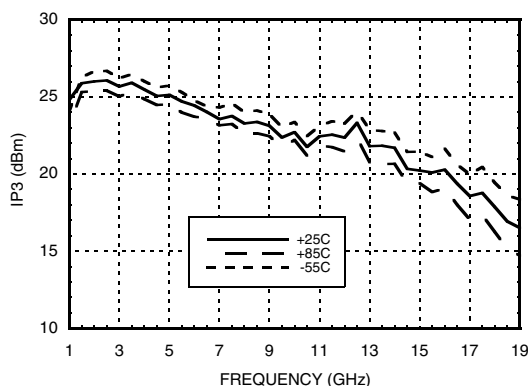
P1dB vs. Temperature



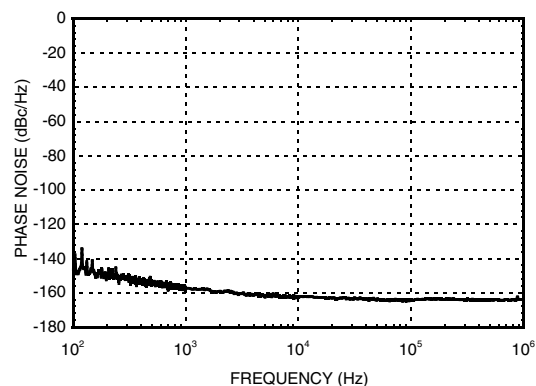
Psat vs. Temperature



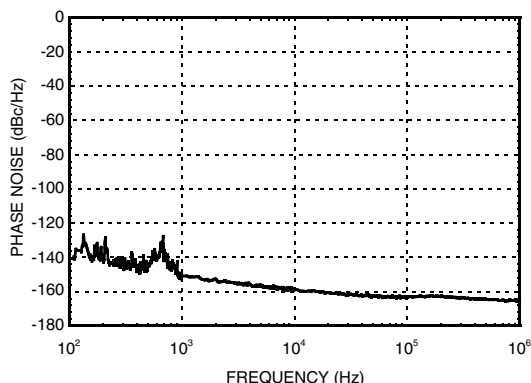
Output IP3 vs. Temperature



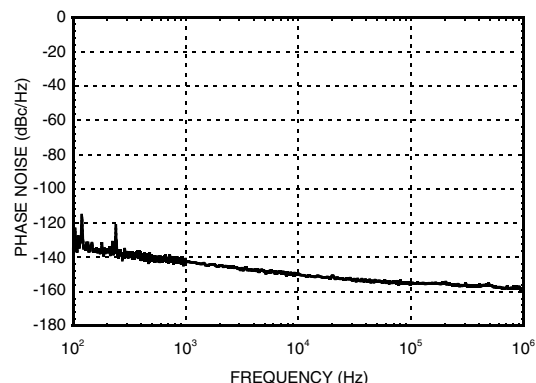
Phase Noise at Pout = 0 dBm @ 2 GHz



Phase Noise at Pout = 0 dBm @ 12 GHz



Phase Noise at Pout = 0 dBm @ 18 GHz





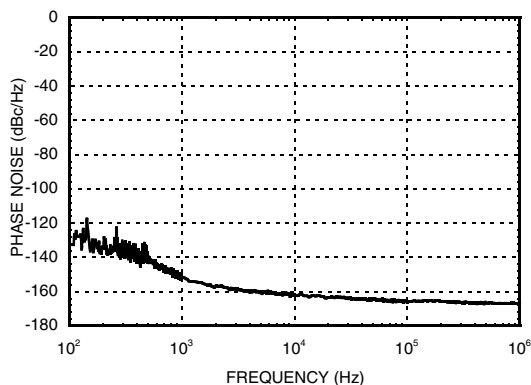
v01.0711



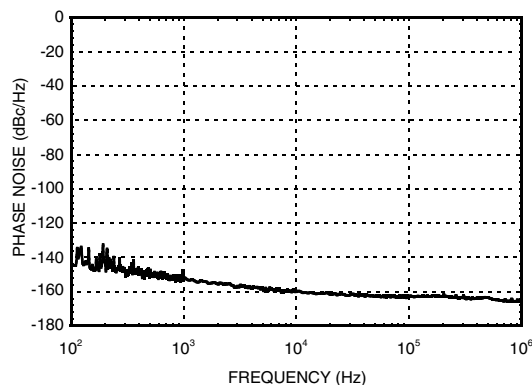
HMC-C050

ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

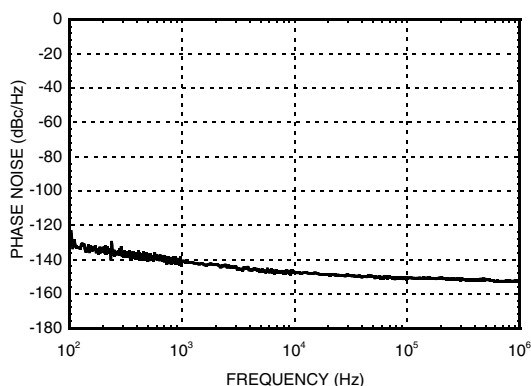
Phase Noise at Psat @ 2 GHz



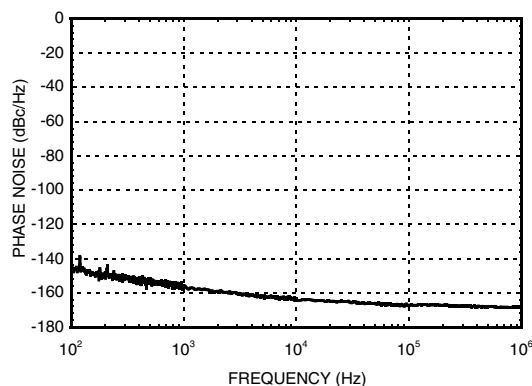
Phase Noise at Psat @ 12 GHz



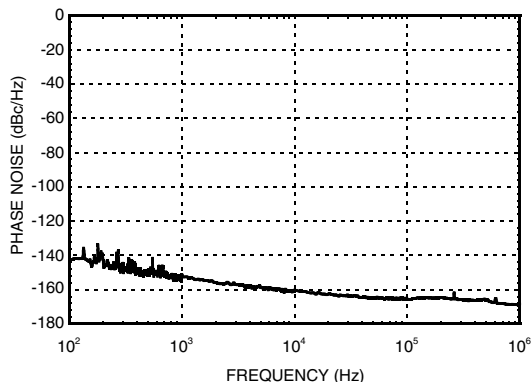
Phase Noise at Psat @ 18 GHz



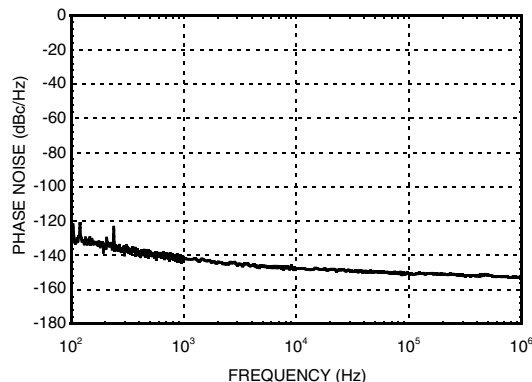
Phase Noise at P1dB @ 2 GHz



Phase Noise at P1dB @ 12 GHz



Phase Noise at P1dB @ 18 GHz





v01.0711

HMC-C050

ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz



Absolute Maximum Ratings

Bias Supply Voltage (Vdc)	+7V
RF Input Power (RFIN)	+15 dBm
Continuous Pdiss (T = 85 °C)	0.65W
Channel Temperature	175 °C
Thermal Resistance	91.5 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
2	Vdc	Power supply voltage for the amplifier.	
3	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
4	GND	Power supply ground.	



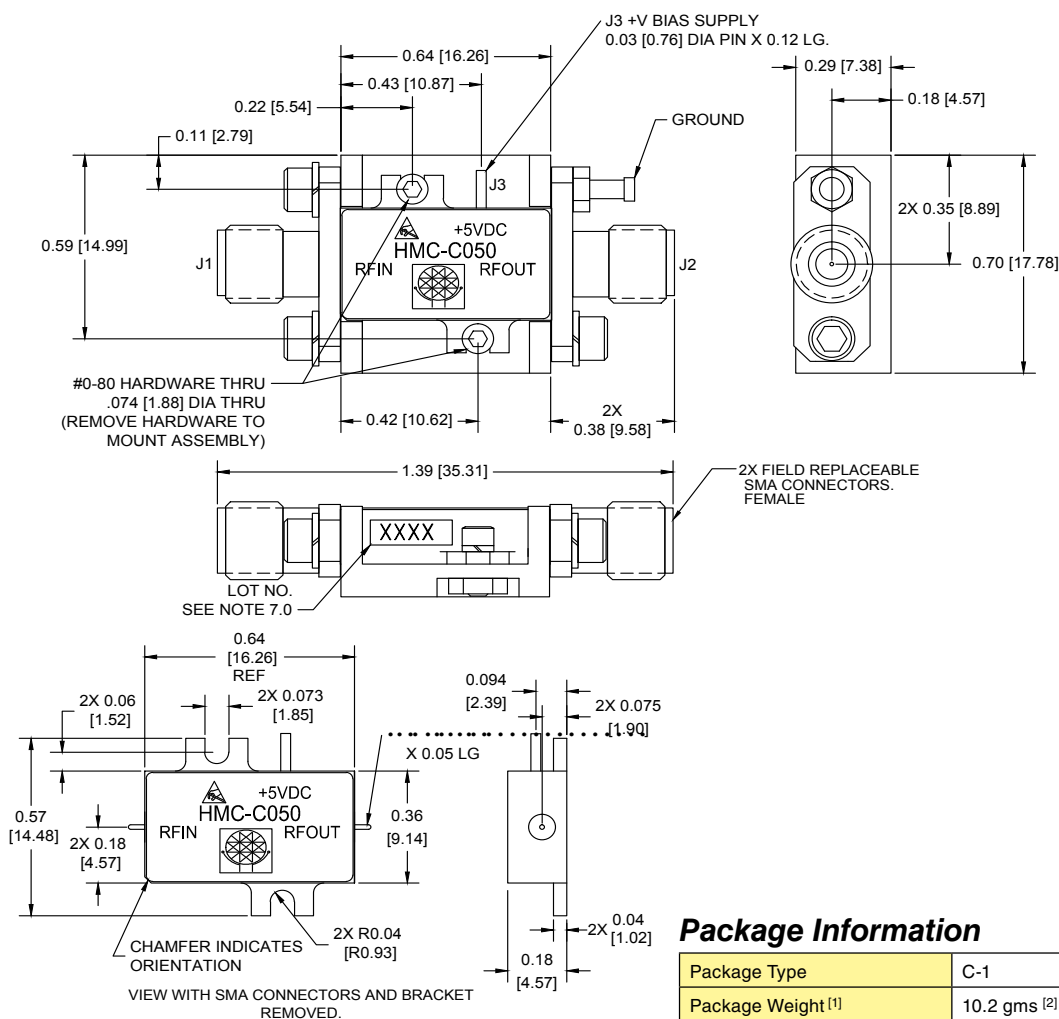
v01.0711



HMC-C050

ULTRA LOW PHASE NOISE DISTRIBUTED AMPLIFIER, 2 - 18 GHz

Outline Drawing



Package Information

Package Type	C-1
Package Weight [1]	10.2 gms [2]
Spacer Weight	N/A

[1] Includes the connectors

[2] ±1 gms Tolerance

NOTES:

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
 2. SPACER MATERIAL: ALUMINUM
 3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
 4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
 5. TOLERANCES ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
 6. FIELD REPLACEABLE SMA CONNECTORS. TENSOLITE 5602-5CCSF OR EQUIVALENT.
- △ TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 - 80 HARDWARE WITH DESIRED MOUNTING SCREWS.